IXYS

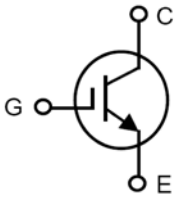
Advance Technical Information

GenX3™ 600V IGBT

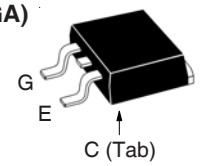
IXGA28N60A3
IXGP28N60A3
IXGH28N60A3

V_{CES} = 600V
I_{C110} = 28A
$V_{CE(sat)}$ ≤ 1.4V

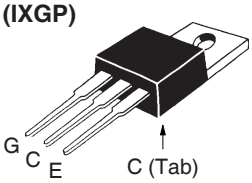
Ultra Low Vsat PT IGBT for up to 5kHz Switching



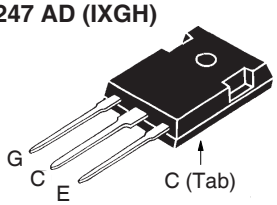
TO-263 (IXGA)



TO-220 (IXGP)



TO-247 AD (IXGH)



G = Gate C = Collector
E = Emitter Tab = Collector

Symbol	Test Conditions	Maximum Ratings	
V_{CES}	T_J = 25°C to 150°C	600	V
V_{CGR}	T_J = 25°C to 150°C, R_{GE} = 1MΩ	600	V
V_{GES}	Continuous	±20	V
V_{GEM}	Transient	±30	V
I_{C25}	T_C = 25°C	75	A
I_{C110}	T_C = 110°C	28	A
I_{CM}	T_C = 25°C, 1ms	170	A
SSOA (RBSOA)	V_{GE} = 15V, T_{VJ} = 125°C, R_G = 10Ω Clamped Inductive Load	I_{CM} = 48 @$V_{CE} \leq V_{CES}$	A
P_C	T_C = 25°C	190	W
T_J		-55 ... +150	°C
T_{JM}		150	°C
T_{stg}		-55 ... +150	°C
T_L	Maximum Lead Temperature for Soldering	300	°C
T_{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C
F_C	Mounting Force (TO-263)	10..65 / 2.2..14.6	N/lb
M_d	Mounting Torque (TO-247 & TO-220)	1.13 / 10	Nm/lb.in
Weight	TO-263	2.5	g
	TO-220	3.0	g
	TO-247	6.0	g

Symbol	Test Conditions (T_J = 25°C, Unless Otherwise Specified)	Characteristic Values Min.	Typ.	Max.	
BV_{CES}	I_C = 250μA, V_{GE} = 0V	600			V
$V_{GE(th)}$	I_C = 250μA, V_{CE} = V_{GE}	3.0		5.0	V
I_{CES}	V_{CE} = V_{CES}, V_{GE} = 0V			25	μA
	T_J = 125°C			250	μA
I_{GES}	V_{CE} = 0V, V_{GE} = ±20V			±100	nA
$V_{CE(sat)}$	I_C = 24A, V_{GE} = 15V, Note 1			1.4	V
	T_J = 125°C		1.3		V

Features

- Optimized for Low Conduction Losses
- Square RBSOA
- International Standard Packages

Advantages

- High Power Density
- Extremely Rugged
- Low Gate Drive Requirement

Applications

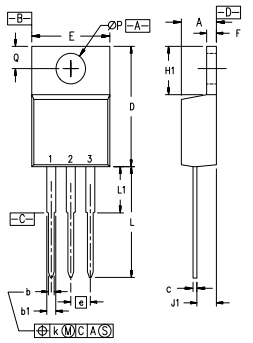
- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts
- Inrush Current Portection Circuits

Symbol	Test Conditions (T_J = 25°C Unless Otherwise Specified)	Characteristic Values Min.	Typ.	Max.
g_{fs}	I_C = 24A, V_{CE} = 10V, Note 1	17	30	S
C_{ies}	V_{CE} = 25V, V_{GE} = 0V, f = 1MHz		1790	pF
C_{oes}			100	pF
C_{res}			26	pF
$Q_{g(on)}$	I_C = 24A, V_{GE} = 15V, V_{CE} = 0.5 • V_{CES}		66	nC
Q_{ge}			13	nC
Q_{gc}			24	nC
$t_{d(on)}$	**Inductive load, T_J = 25°C**		18	ns
t_{ri}	I_C = 24A, V_{GE} = 15V		26	ns
E_{on}	V_{CE} = 480V, R_G = 10Ω		0.7	mJ
$t_{d(off)}$	Note 2		300	ns
t_{fi}			260	ns
E_{off}			2.4	mJ
$t_{d(on)}$	**Inductive load, T_J = 125°C**		20	ns
t_{ri}	I_C = 24A, V_{GE} = 15V		26	ns
E_{on}	V_{CE} = 480V, R_G = 10Ω		1.4	mJ
$t_{d(off)}$	Note 2		470	ns
t_{fi}			400	ns
E_{off}			4.2	mJ
R_{thJC}				0.66 °C/W
R_{thCS}	TO-220		0.50	°C/W
R_{thCS}	TO-247		0.21	°C/W

Notes:

1. Pulse test, t ≤ 300µs, duty cycle, d ≤ 2%.
2. Switching times & energy losses may increase for higher V_{CE}(clamp), T_J or R_G.

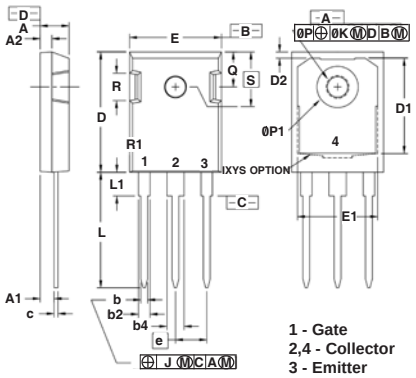
TO-220 Outline



Pins: 1 - Gate 2 - Collector
3 - Emitter

SYM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.170	.190	4.32	4.83
b	.025	.040	0.64	1.02
b1	.045	.065	1.15	1.65
c	.014	.022	0.35	0.56
D	.580	.630	14.73	16.00
E	.390	.420	9.91	10.66
e	.100 BSC		2.54 BSC	
F	.045	.055	1.14	1.40
H1	.230	.270	5.85	6.85
J1	.090	.110	2.29	2.79
k	0	.015	0	0.38
L	.500	.550	12.70	13.97
L1	.110	.230	2.79	5.84
ØP	.139	.161	3.53	4.08
Q	.100	.125	2.54	3.18

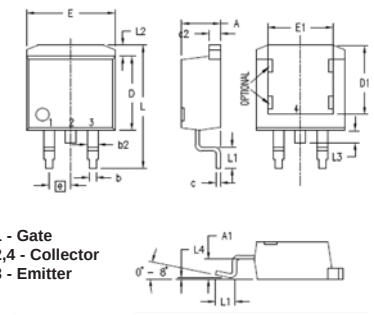
TO-247 Outline



1 - Gate
2,4 - Collector
3 - Emitter

SYM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.690	16.51	17.53
D2	.035	.050	0.89	1.27
E	.620	.635	15.75	16.13
E1	.545	.565	13.84	14.35
e	.215 BSC		5.45 BSC	
J	--	.010	--	0.25
K	--	.025	--	0.64
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
øP	.140	.144	3.55	3.65
øP1	.275	.290	6.99	7.37
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.242 BSC		6.15 BSC	

TO-263 Outline



1 - Gate
2,4 - Collector
3 - Emitter

SYM	INCHES MIN	INCHES MAX	MILLIMETERS MIN	MILLIMETERS MAX
A	.160	.190	4.06	4.83
A1	.080	.110	2.03	2.79
b	.020	.039	0.51	0.99
b2	.045	.055	1.14	1.40
c	.016	.029	0.40	0.74
c2	.045	.055	1.14	1.40
D	.340	.380	8.64	9.65
D1	.315	.350	8.00	8.89
E	.380	.410	9.65	10.41
E1	.245	.320	6.22	8.13
e	.100 BSC		2.54 BSC	
L	.575	.625	14.61	15.88
L1	.090	.110	2.29	2.79
L2	.040	.055	1.02	1.40
L3	.050	.070	1.27	1.78
L4	0	.005	0	0.13

ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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Fig. 1. Output Characteristics @ T_J = 25ºC

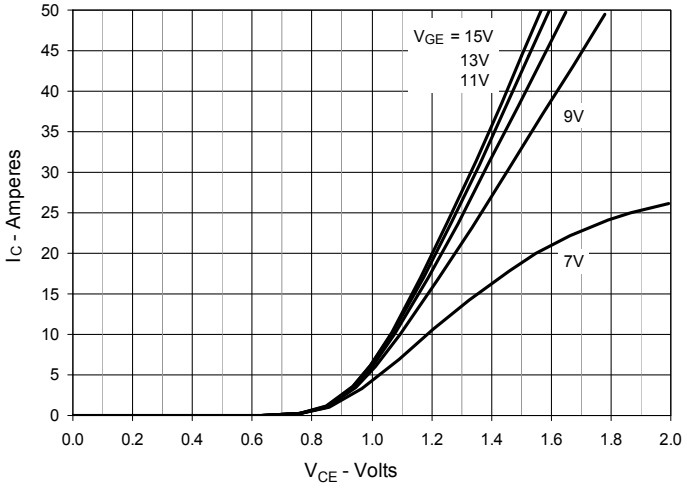

Fig. 2. Extended Output Characteristics @ T_J = 25ºC

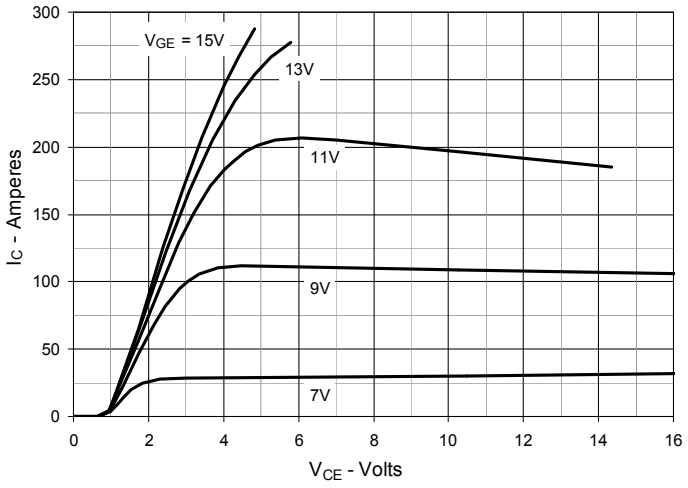

Fig. 3. Output Characteristics @ T_J = 125ºC

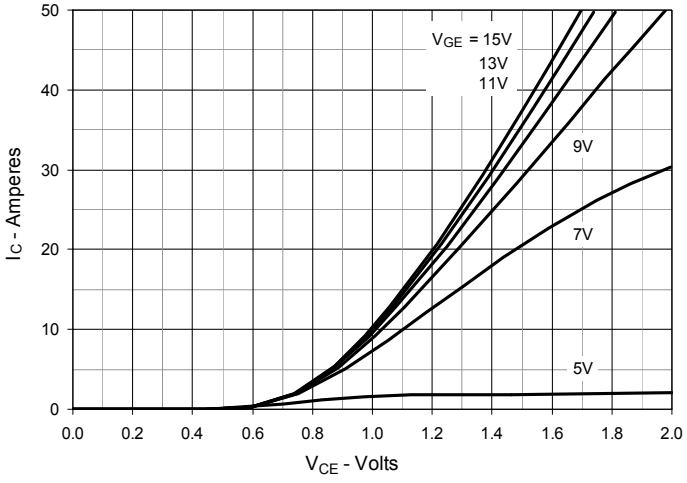

Fig. 4. Dependence of $V_{CE(sat)}$ on Junction Temperature

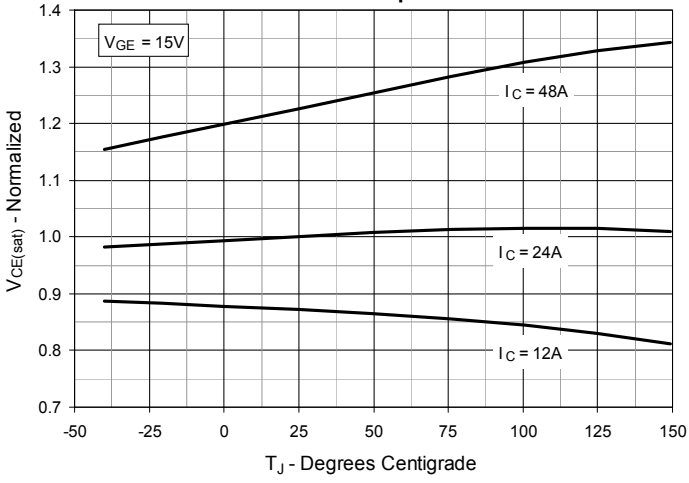

Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage

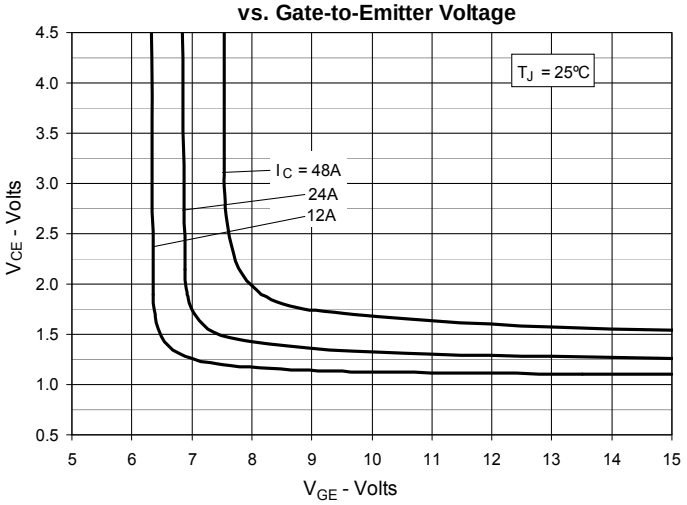

Fig. 6. Input Admittance

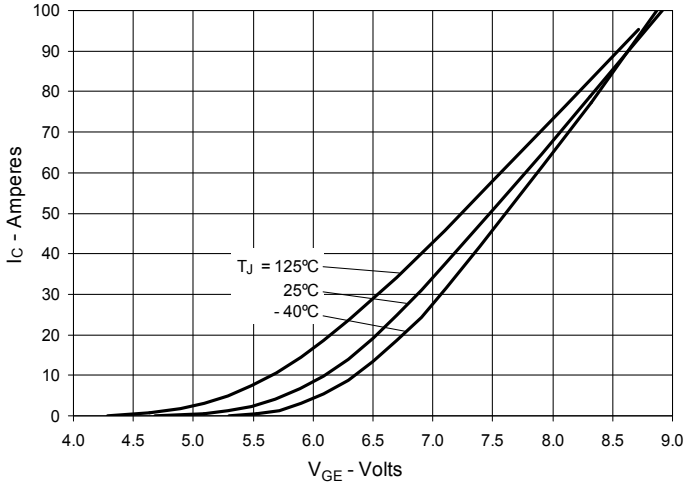

Fig. 7. Transconductance

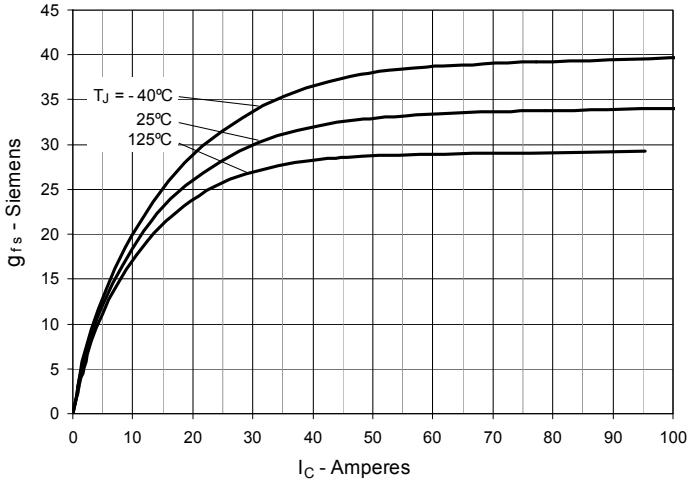

Fig. 8. Gate Charge

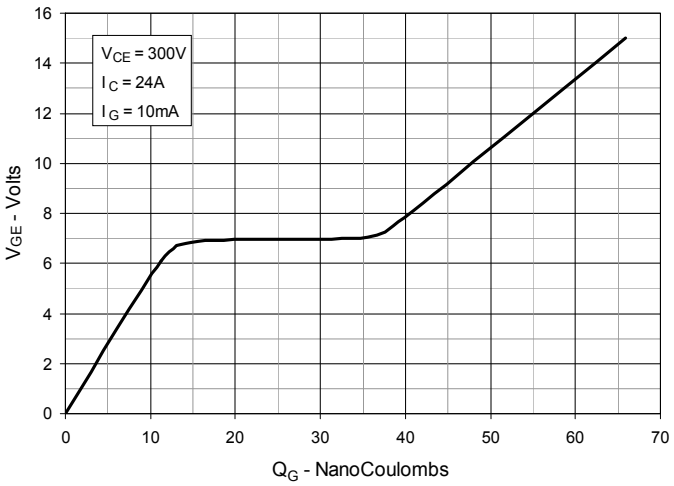

Fig. 9. Reverse-Bias Safe Operating Area

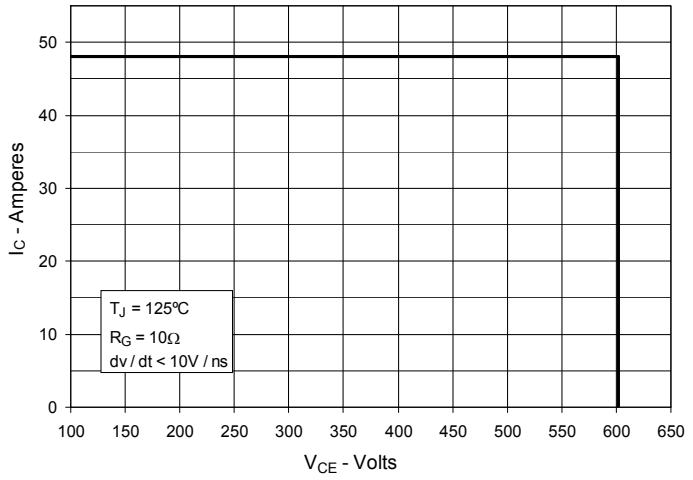

Fig. 10. Capacitance

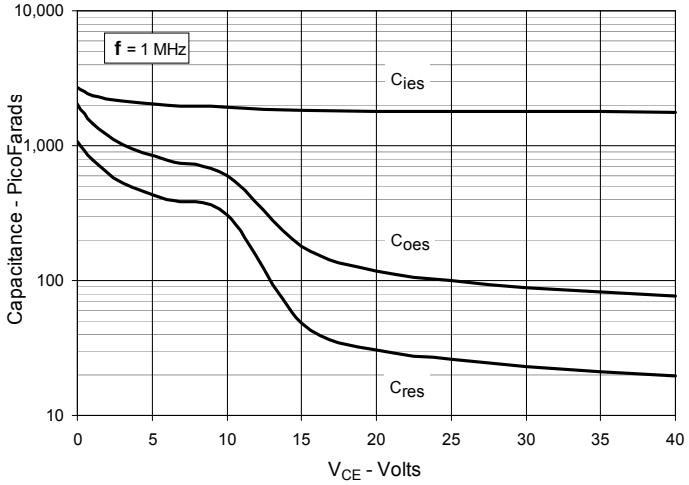

Fig. 11. Maximum Transient Thermal Impedance

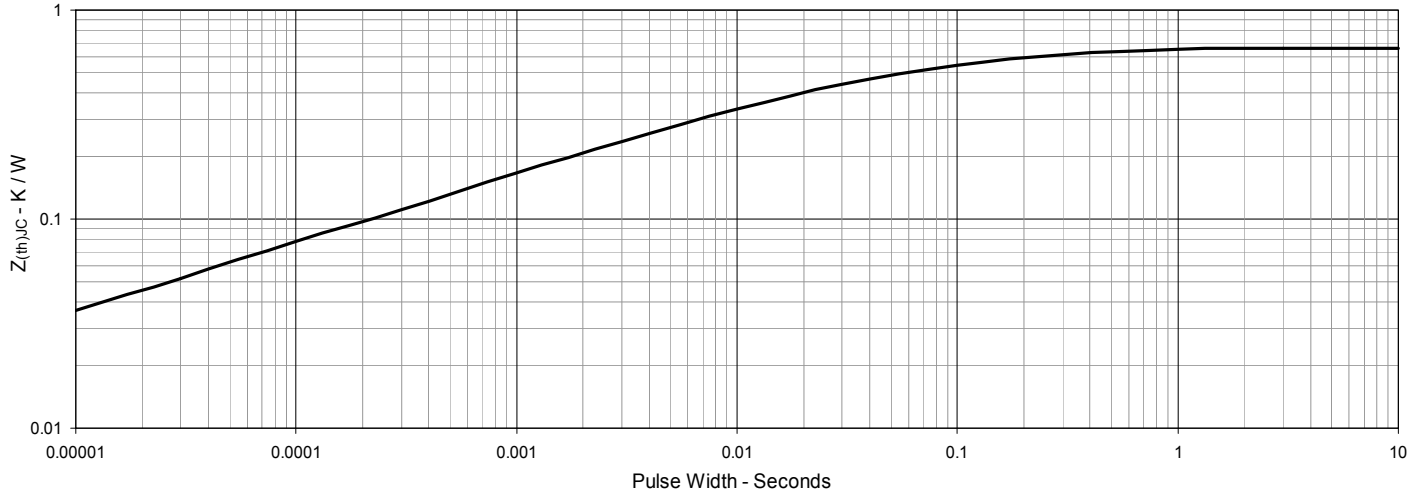

Fig. 12. Inductive Switching Energy Loss vs. Gate Resistance

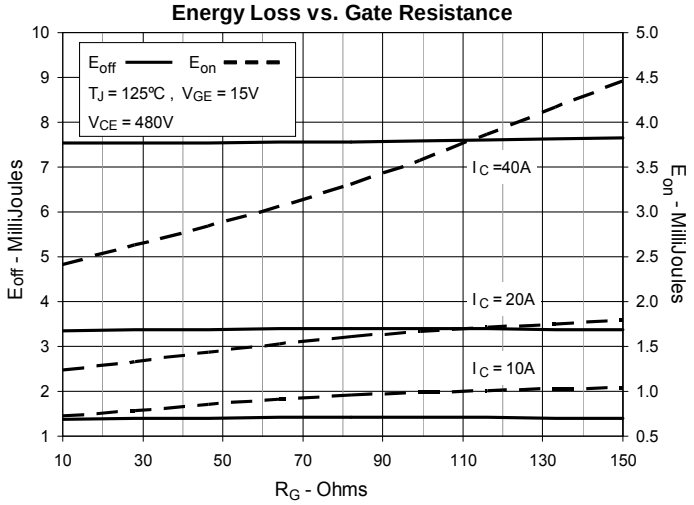

Fig. 13. Inductive Switching Energy Loss vs. Junction Temperature

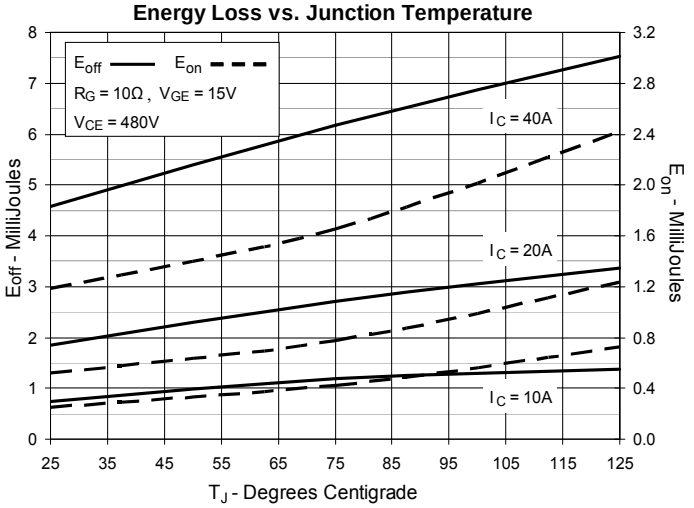

Fig. 14. Inductive Switching Energy Loss vs. Collector Current

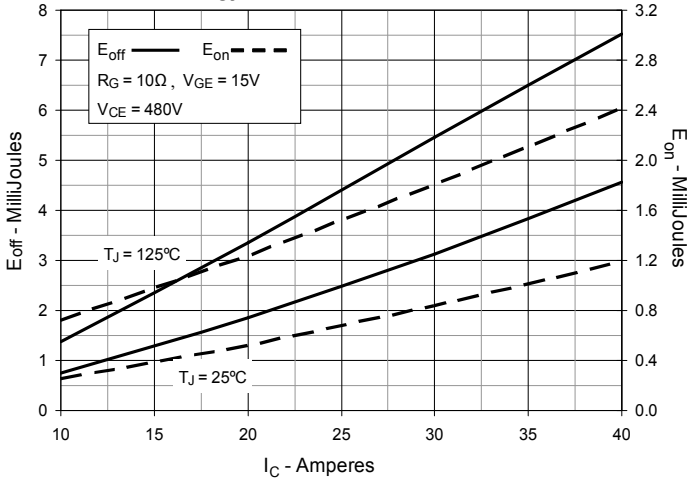

Fig. 15. Inductive Turn-off Switching Times vs. Gate Resistance

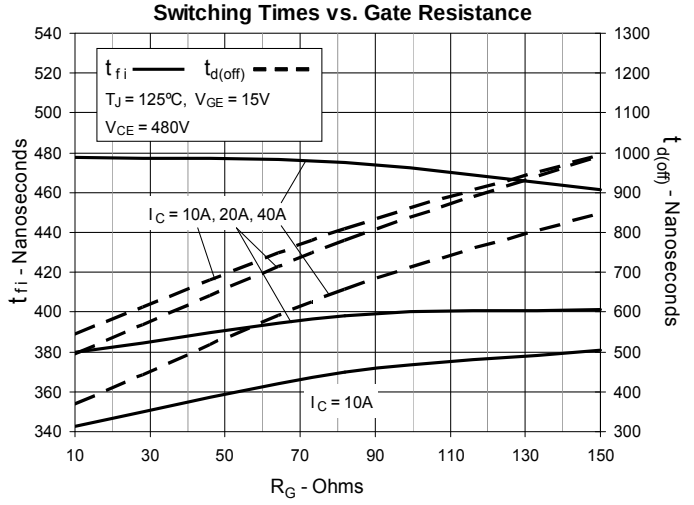

Fig. 16. Inductive Turn-off Switching Times vs. Collector Current

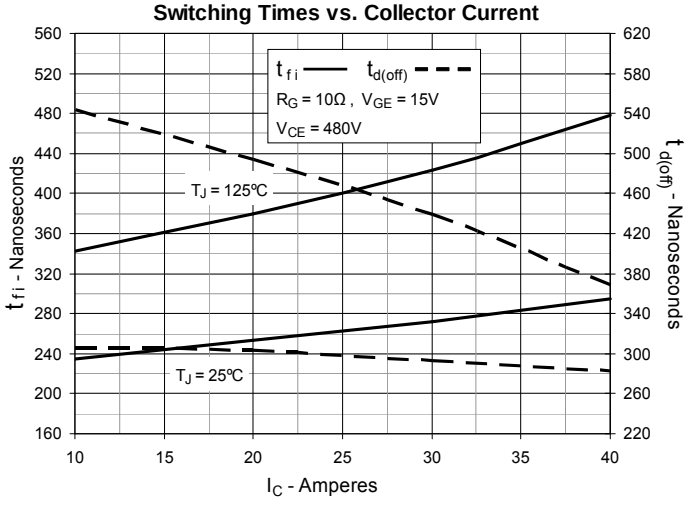

Fig. 17. Inductive Turn-off Switching Times vs. Junction Temperature

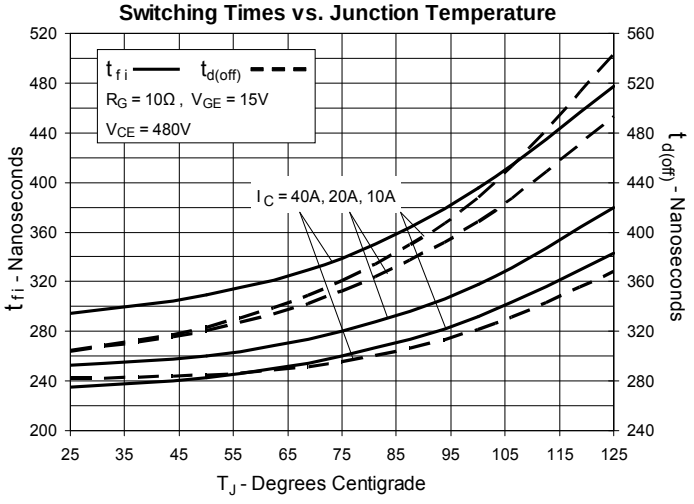

Fig. 18. Inductive Turn-on Switching Times vs. Gate Resistance

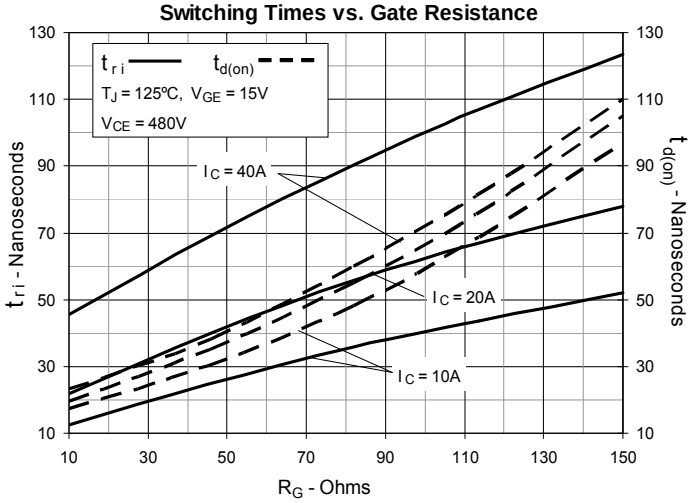

Fig. 19. Inductive Turn-on Switching Times vs. Junction Temperature

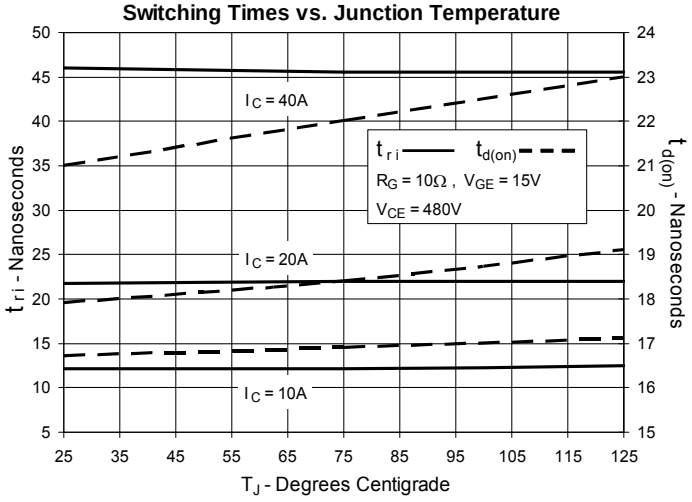

Fig. 20. Inductive Turn-on Switching Times vs. Collector Current